

TQP7M9104

2W High Linearity Amplifier



Applications

- Repeaters
- BTS Transceivers
- BTS High Power Amplifiers
- CDMA / WCDMA / LTE
- General Purpose Wireless

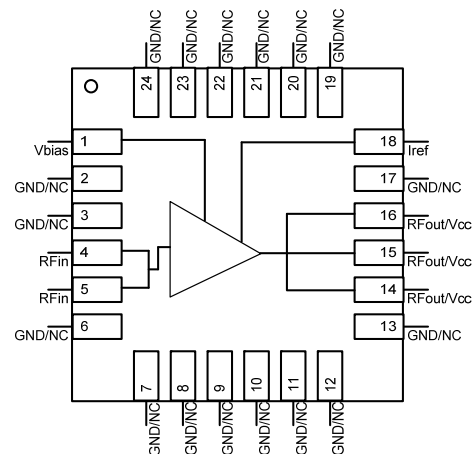
Product Features

- 700-4000 MHz
- +32.8 dBm P1dB
- +49.5 dBm Output IP3
- 15.8 dB Gain @ 2140 MHz
- +5V Single Supply, 435 mA Collector Current
- Internal RF overdrive protection
- Internal DC overvoltage protection
- Internal Active Bias
- On chip ESD protection
- Shut-down Capability
- Capable of handling 10:1 VSWR @ 5Vcc, 2.14 GHz, 32.8 dBm CW Pout or 23.5 dBm WCDMA Pout



24-pin QFN 4x4mm SMT Package

Functional Block Diagram



General Description

The TQP7M9104 is a high linearity driver amplifier in industry standard, RoHS compliant, QFN surface mount package. This InGaP/GaAs HBT delivers high performance across 700-4000 GHz range of frequencies with 15.8 dB Gain, +49.5 dBm OIP3 and +32.5 dBm P1dB at 2.14 GHz while only consuming 435 mA quiescent collector current. All devices are 100% RF and DC tested.

The TQP7M9104 incorporates on-chip features that differentiate it from other products in the market. The amplifier integrates an on-chip DC over-voltage and RF over-drive protection. This protects the amplifier from electrical DC voltage surges and high input RF input power levels that may occur in a system.

The TQP7M9104 is targeted for use as a driver amplifier in wireless infrastructure where high linearity, medium power, and high efficiency are required. The device is an excellent candidate for transceiver line cards and high power amplifiers in current and next generation multi-carrier 3G / 4G base stations.

Pin Configuration

Pin #	Symbol
1	Vbias
2, 3, 6, 7, 8, 9, 10, 11, 12, 13, 17, 19, 20, 21, 22, 23, 24	GND / NC
4, 5	RFIn
14, 15, 16	RFout/Vcc
18	Iref

Ordering Information

Part No.	Description
TQP7M9104	2 W High Linearity Amplifier
TQP7M9104-PCB900	TQP7M9104 920-960MHz EVB
TQP7M9104-PCB2140	TQP7M9104 2.11-2.17GHz EVB

Standard T/R size =2500 pieces on a 13" reel.

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Specifications

Absolute Maximum Ratings

Parameter	Rating
Storage Temperature	-65 to +150 °C
Device Voltage, V_{cc}	6.5 V
Maximum Input Power, CW	+30 dBm

Operation of this device outside the parameter ranges given above may cause permanent damage.

Recommended Operating Conditions

Parameter	Min	Typ	Max	Units
V_{cc}		+5	+5.25	V
T_{case}	-40		+85	°C
T_j (for >10 ⁶ hours MTTF)			160	°C

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

Electrical Specifications

Test Conditions: $V_{CC} = +5V$, $I_{CQ} = 435$ mA, $T = 25^\circ C$ using a TQP7M9104-PCB2140 application circuit.

Parameter	Conditions	Min	Typical	Max	Units
Operational Bandwidth		700		4000	MHz
Test Frequency			2140		MHz
Power Gain			15.8		dB
Input Return Loss			12		dB
Output Return Loss			9.5		dB
Output IP3 (+17 dBm/tone, $\Delta f = 1$ MHz)	See Note 1.		+49.5		dBm
WCDMA Channel Power (at -50 dBc ACLR)	See Note 2.		23.8		dBm
Output P1dB			+32.8		dBm
Noise Figure			4.4		dB
Quiescent Collector Current, I_{cq}			435		mA
V_{cc}			+5		V
I_{ref}			19		mA
Thermal Resistance (jnc to case) θ_{jc}			15.7		°C/W

Notes:

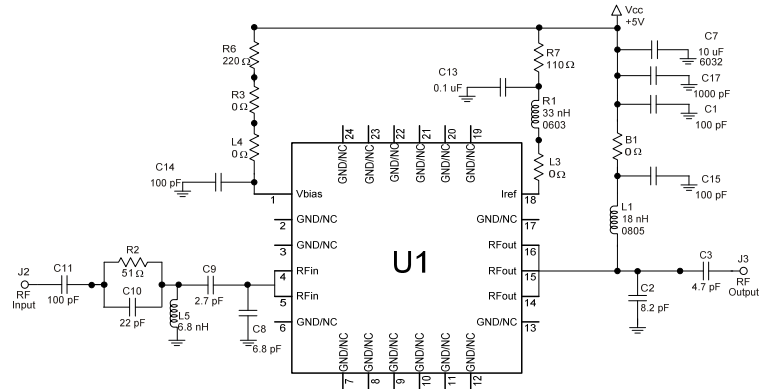
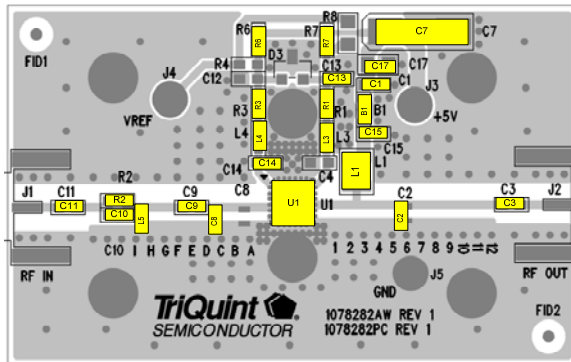
- OIP3 is measured with 1 MHz tone spacing.
- Using W-CDMA 3GPP Test Model 1+64 DPCH, PAR = 9.7 dB @ 0.01% Probability, 3.84 MHz BW

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Application Circuit 920-960 MHz (TQP7M9104-PCB900)



Notes:

1. See PC Board Layout under Application Information section for more information.
2. Components shown on the silkscreen but not on the schematic are not used.
3. 0 Ω resistor may be replaced with copper trace in the target application layout.
4. Iref can be used as device power down current by placing R7 at location R8.
5. The recommended component values are dependent upon the frequency of operation.
6. All components are of 0603 size unless stated on the schematic.
7. R1 is critical for device linearity performance.
8. Critical component placement locations:
 - Distance between center of C8 and TQP7M9104 (U1) device package is 190 mil.
 - Distance between center of L5 and TQP7M9104 (U1) device package is 452 mil.
 - Distance between center of C2 and TQP7M9104 (U1) device package is 305 mil.
 - Distance between center of C9 and TQP7M9104 (U1) device package is 275 mil.

Bill of Material

Ref Des	Value	Description	Manuf.	Part Number
U1	n/a	2W High Linearity Amplifier	TriQuint	TQP7M9104
n/a	n/a	Printed Circuit Board	TriQuint	1078282
C8	6.8 pF	Capacitor, Chip, 0603, ± 0.05 pF, 50 V, Accu-P	AVX	06035J6R8ABSTR
C9	2.7 pF	Capacitor, Chip, 0603, ± 0.05 pF, 50 V, Accu-P	AVX	06035J2R7ABSTR
B1, L3, L4, R3	0 Ω	Resistor, Chip, 0603, 5%, 1/16W	various	
L5	6.8 nH	Inductor, 0603, 5%	Toko	LL1608-FSL6N8
C3	4.7 pF	Capacitor, Chip, 0603, ± 0.05 pF, 50 V, Accu-P	AVX	06035J4R7ABSTR
C2	8.2 pF	Capacitor, Chip, 0603, ± 0.05 pF, 50 V, Accu-P	AVX	06035J8R2ABSTR
C10	22 pF	Capacitor, Chip, 0603, 5%, 50 V, NPO/COG	various	
C1, C14, C15, C11	100 pF	Capacitor, Chip, 0603, 5%, 50V, NPO/COG	various	
L1	18 nH	Inductor, 0805, 5%, Coilcraft CS Series	Coilcraft	0805CS-330XJLB
C17	1000 pF	Capacitor, Chip, 0603, 10%, 50V, NPO/COG	various	
C13	0.1 uF	Capacitor, Chip, 0603, 50V, X5R, 10%	various	
C7	10 uF	Capacitor, Tantalum, 6032, 35V, 10%	various	
R2	51 Ω	Resistor, Chip, 0603, 5%, 1/16W	various	
R6	220 Ω	Resistor, Chip, 0603, 1%, 1/16W	various	
R7	110 Ω	Resistor, Chip, 0603, 1%, 1/16W	various	
R1	33 nH	Inductor, 0603, 5%	Toko	LL1608-FSL33N
R8, R4, C12, C4, D3	n/a	Do Not Place		

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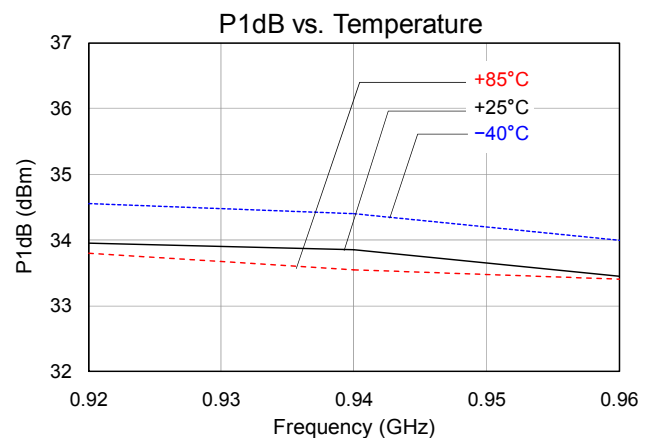
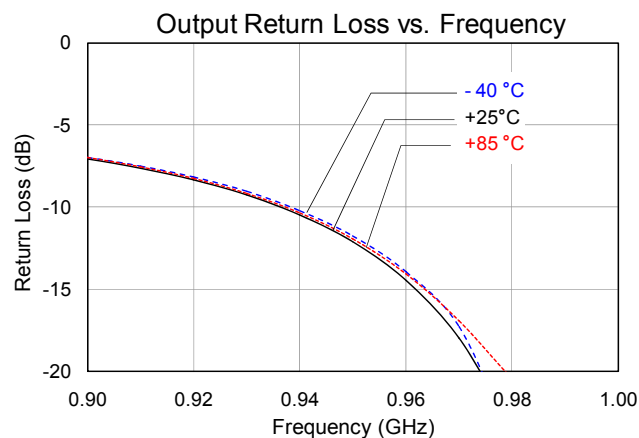
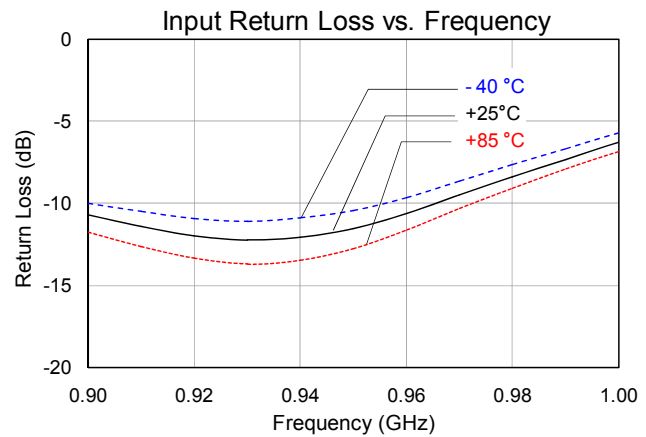
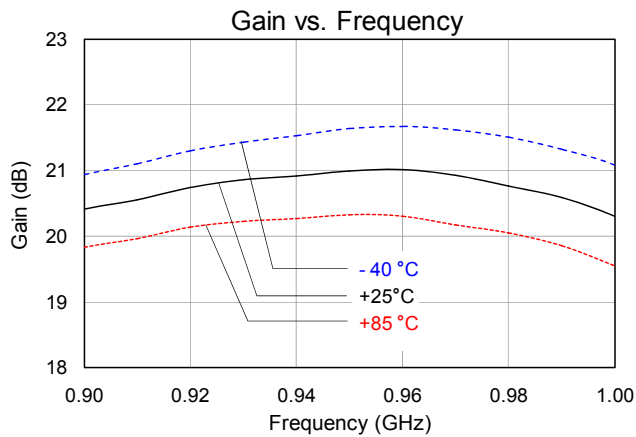
Typical Performance 920-960 MHz

Frequency	MHz	920	940	960
Gain	dB	20.8	21	21
Input Return Loss	dB	-13	-12	-11
Output Return Loss	dB	-9	-11.8	-15
Output P1dB	dBm	+33.9	+33.8	+33.4
Output IP3 (+23 dBm/tone, $\Delta f = 1$ MHz)	dBm	+45	+45	+45
WCDMA Channel power (at -50 dBc ACLR) [1]	dBm	+24	+23.5	+23
Supply Voltage, Vcc	V	+5		
Quiescent Collector Current, Icq	mA	435		
Reference Current, Iref	mA	19		

Notes:

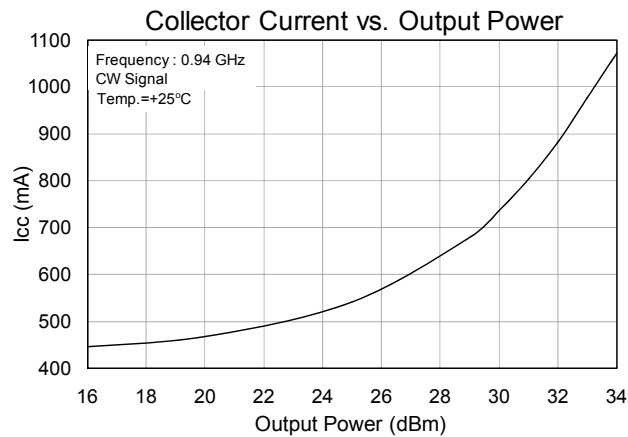
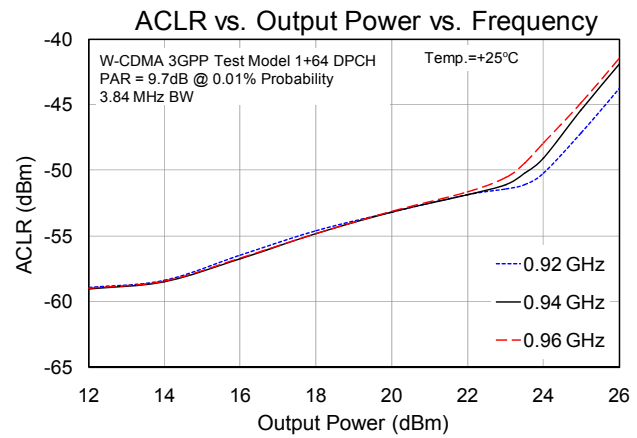
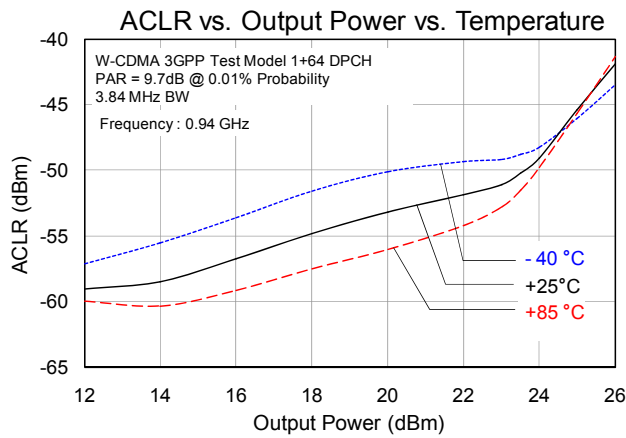
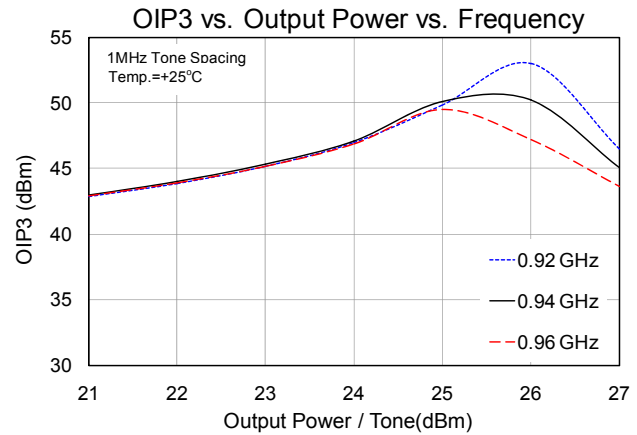
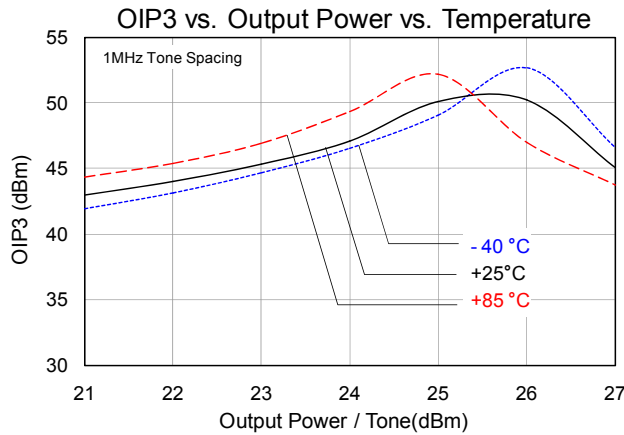
1. ACLR Test set-up: 3GPP WCDMA, TM1+64 DPCH, +5 MHz offset, PAR = 9.7 dB at 0.01% Prob.

RF Performance Plots 920-960 MHz



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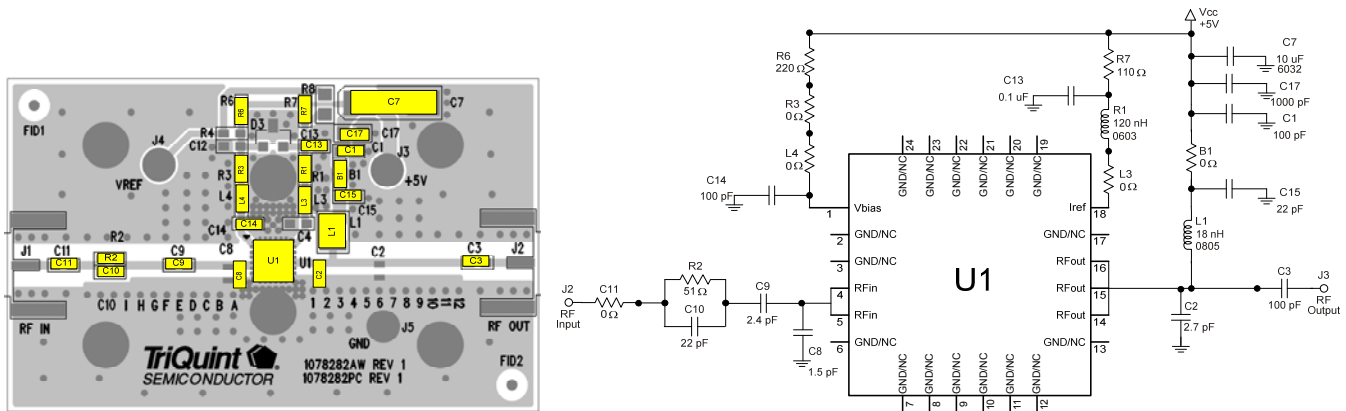


TQP7M9104

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Application Circuit 2110-2170 MHz (TQP7M9104-PCB2140)



Notes:

1. See PC Board Layout under Application Information section for more information.
2. Components shown on the silkscreen but not on the schematic are not used.
3. 0 Ω resistor may be replaced with copper trace in the target application layout.
4. Iref can be used as device power down current by placing R7 at location R8.
5. The recommended component values are dependent upon the frequency of operation.
6. All components are of 0603 size unless stated on the schematic.
7. R1 is critical for device linearity performance.
8. Critical component placement locations:
 Distance between center of C8 and TQP7M9104 (U1) device package is 50 mil.
 Distance between center of C2 and TQP7M9104 (U1) device package is 113 mil.
 Distance between center of C9 and TQP7M9104 (U1) device package is 275 mil.

Bill of Material

Ref Des	Value	Description	Manuf.	Part Number
U1	n/a	2W High Linearity Amplifier	TriQuint	TQP7M9104
n/a	n/a	Printed Circuit Board	TriQuint	1078282
C8	1.5 pF	Capacitor, Chip, 0603, ± 0.05 pF, 50V, Accu-P	AVX	06035J1R5ABSTR
C9	2.4 pF	Capacitor, Chip, 0603, ± 0.05 pF, 50V, Accu-P	AVX	06035J2R4ABSTR
C2	2.7 pF	Capacitor, Chip, 0603, ± 0.05 pF, 50V, Accu-P	AVX	06035J2R7ABSTR
B1, L3, L4, R3, C11	0 Ω	Resistor, Chip, 0603, 5%, 1/16W	various	
C10, C15	22 pF	Capacitor, Chip, 0603, 5%, 50V, NPO/COG	various	
C1, C14, C3	100 pF	Capacitor, Chip, 0603, 5%, 50V, NPO/COG	various	
L1	18 nH	Inductor, 1008, 5%, Ceramic	Coilcraft	1008HQ-18NXJL
C17	1000 pF	Capacitor, Chip, 0603, 10%, 50V, NPO/COG	various	
C13	0.1 uF	Capacitor, Chip, 0603, 10%, 50V, X5R	various	
C7	10 uF	Capacitor, Tantalum, 6032, 20 %, 50V	various	
R2	51 Ω	Resistor, Chip, 0603, 5%, 1/16W	various	
R6	220 Ω	Resistor, Chip, 0603, 1%, 1/16W	various	
R7	110 Ω	Resistor, Chip, 0603, 1%, 1/16W	various	
R1	120 nH	Inductor, 0603, 5%	Toko	LL1608-FSLR12J
R8, R4, C12, C4, D3	n/a	Do Not Place		

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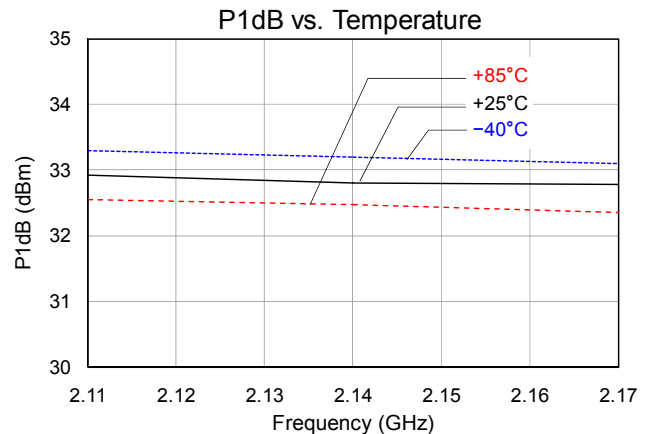
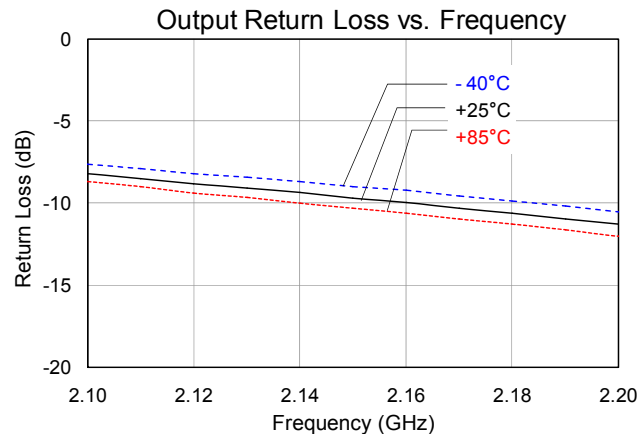
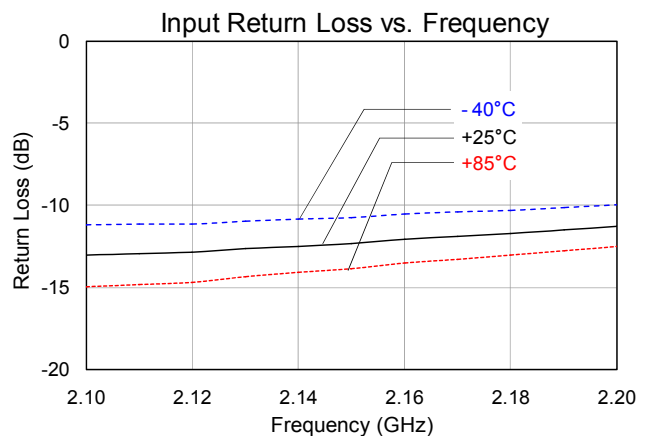
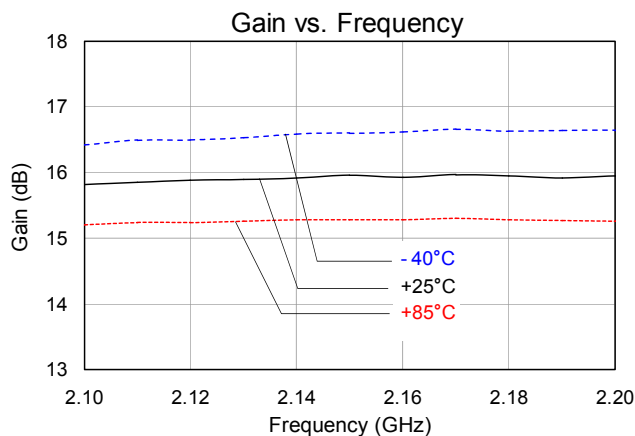
Typical Performance 2110-2170 MHz

Frequency	MHz	2110	2140	2170
Gain	dB	15.8	15.8	15.8
Input Return Loss	dB	-12.4	-12.0	-11.8
Output Return Loss	dB	-8.7	-9.5	-10.5
Output P1dB	dBm	+32.9	+32.8	+32.8
Output IP3 (+17 dBm/tone, $\Delta f = 1$ MHz)	dBm	+49	+49.5	+50
WCDMA Channel power (at -50 dBc ACLR) [1]	dBm	+23.5	+23.8	+24.0
Noise Figure	dB	4.4	4.4	4.6
Supply Voltage, Vcc	V	+5		
Quiescent Collector Current, Icq	mA	435		
Reference Current, Iref	mA	19		

Notes:

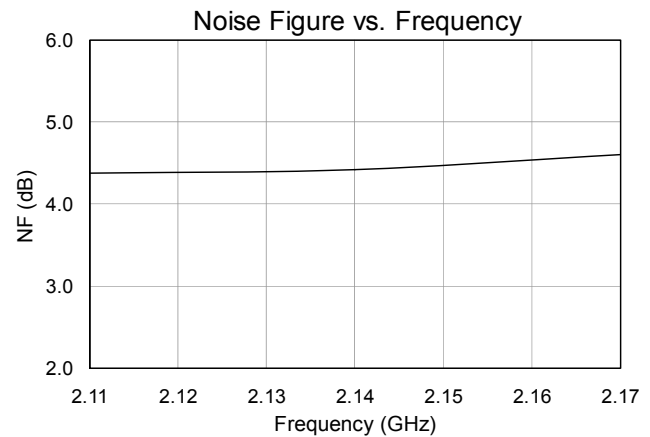
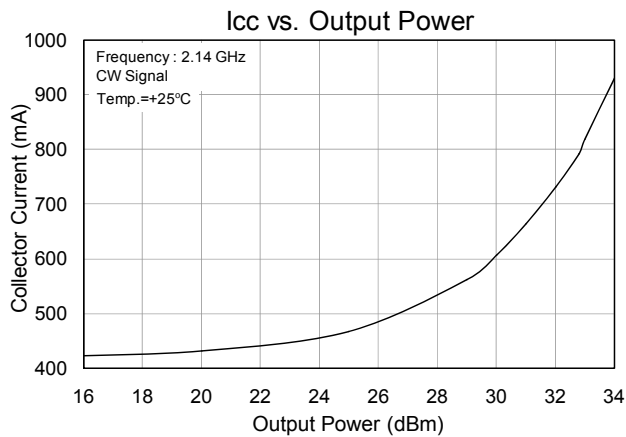
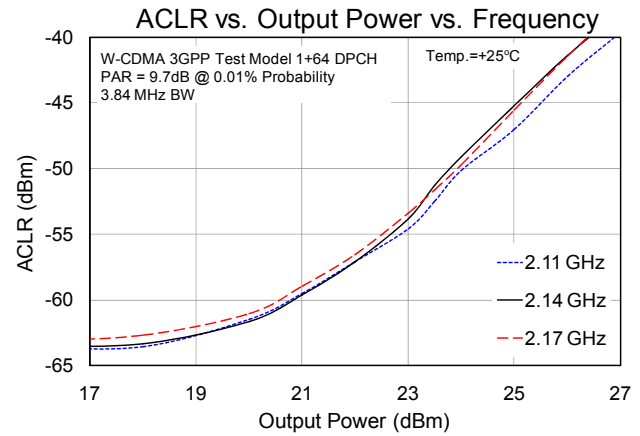
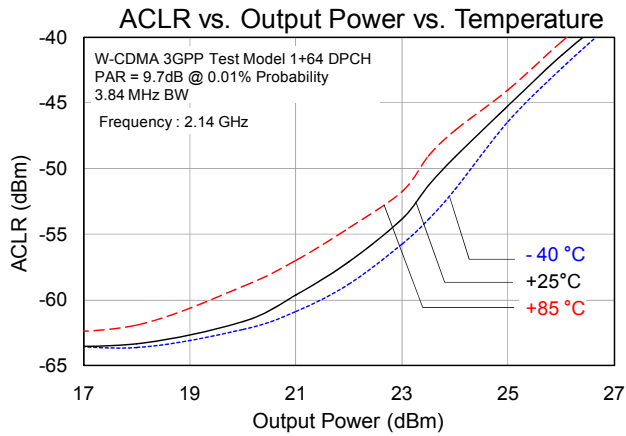
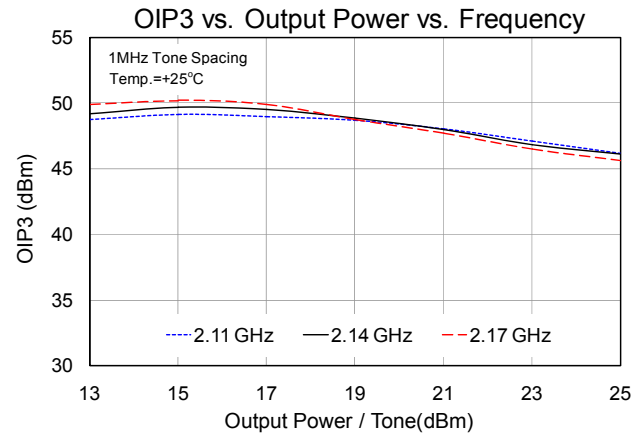
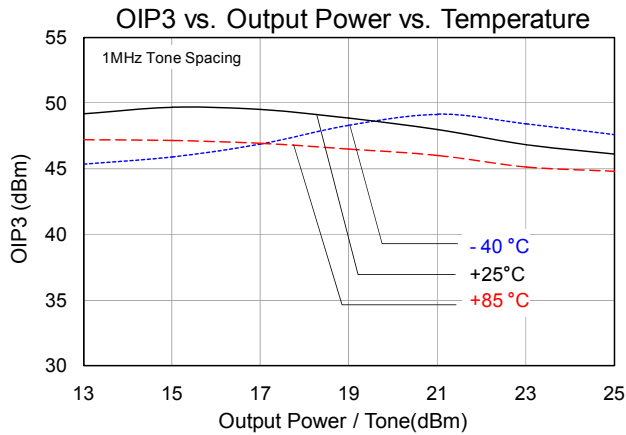
1. ACLR Test set-up: 3GPP WCDMA, TM1+64 DPCH, +5 MHz offset, PAR = 9.7 dB at 0.01% Prob.

RF Performance Plots 2110-2170 MHz



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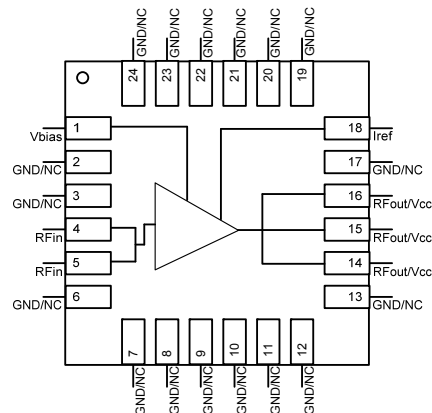


TQP7M9104

2W High Linearity Amplifier



Pin Configuration and Description



Pin	Symbol	Description
1	Vbias	Voltage supply for active bias for the amp. Connect to same supply voltage as Vcc.
2, 3, 6, 7, 8, 9, 10, 11, 12, 13, 17, 19, 20, 21, 22, 23, 24	GND/NC	No internal connection. This pin can be grounded or N/C on PCB. Land pads should be provided for PCB mounting integrity.
4, 5	RFIn	RF Input. DC voltage present, blocking capacitor required. Requires external match for optimal performance.
14, 15, 16	RFout / Vcc	RF Output. DC Voltage present, blocking cap required. Requires external match for optimal performance.
18	Iref	Reference current into internal active bias current mirror. Current into Iref sets device quiescent current. Also, can be used as on/off control.
Backside paddle	RF/DC GND	Multiple Vias should be employed to minimize inductance and thermal resistance. Use recommended via pattern shown under mounting configuration and ensure good solder attach for optimum thermal and electrical performance

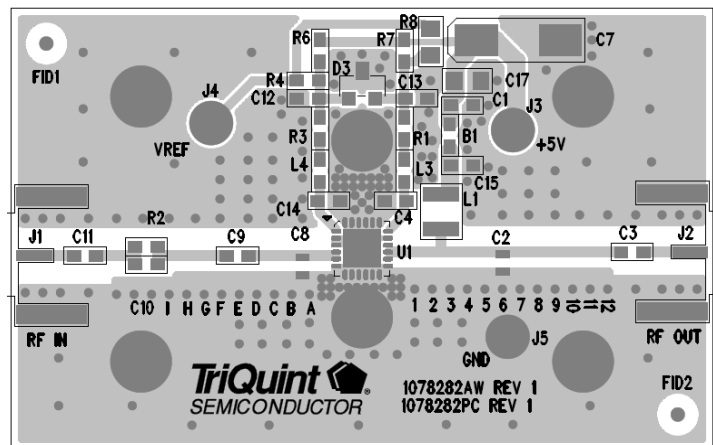
Applications Information

PC Board Layout

PCB Material (stackup):

- 1 oz. Cu top layer
- 0.014 inch Nelco N4000-13, $\epsilon_r=3.7$
- 1 oz. Cu middle layer 1
- Core Nelco N4000-13
- 1 oz. Cu middle layer 2
- 0.014 inch Nelco N-4000-13
- 1 oz. Cu bottom layer
- Finished board thickness is 0.062±.006
- 50 ohm line dimensions: width = .028"

The pad pattern shown has been developed and tested for optimized assembly at TriQuint Semiconductor. The PCB land pattern has been developed to accommodate lead and package tolerances. Since surface mount processes vary from supplier to supplier, careful process development is recommended.



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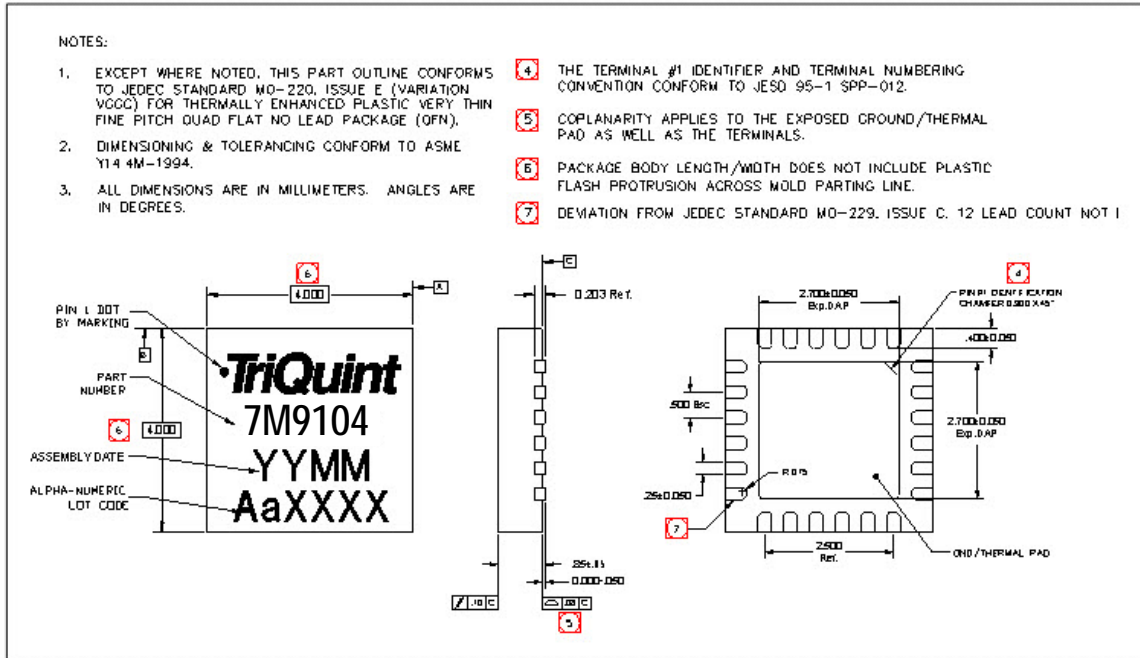


Mechanical Information

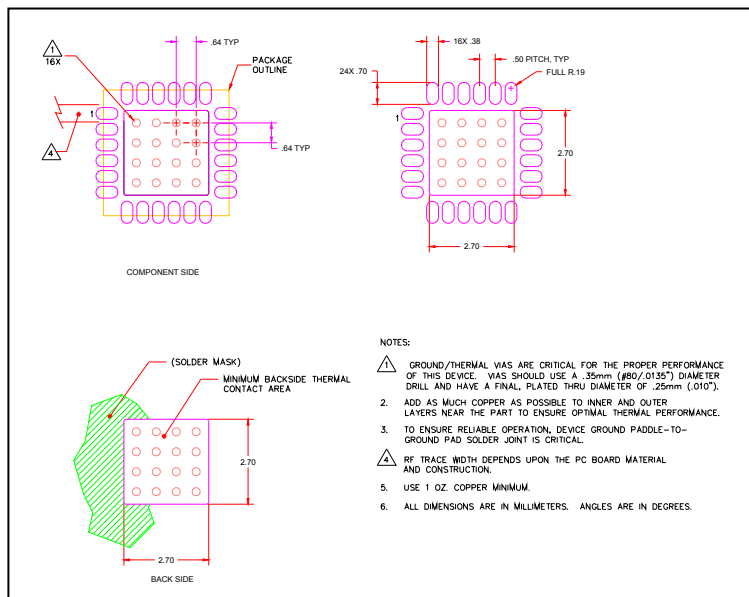
Package Information and Dimensions

This package is lead-free, RoHS-compliant, and green. The plating material on the pins is annealed matte tin over copper. It is compatible with both lead-free (maximum 260 °C reflow temperature) and leaded (maximum 245 °C reflow temperature) soldering processes.

The component will be laser marked with “7M9104” product label with an alphanumeric lot code on the top surface of the package.



Mounting Configuration



All dimensions are in millimeters (inches). Angles are in degrees.

Notes:

- Ground vias are critical for the proper RF performance of this device. Vias should use a .35mm (#80 / .0135") diameter drill and have a final plated thru diameter of .25mm (.010").
- Add as much copper as possible to inner and outer layers near the part to ensure optimal thermal performance.

Product Compliance Information

ESD Information



Caution! ESD-Sensitive Device

ESD Rating: Class 1C
Value: ≥ 1000 V and < 2000 V
Test: Human Body Model (HBM)
Standard: JEDEC Standard JESD22-A114

ESD Rating: Class IV
Value: ≥ 1000 V min
Test: Charged Device Model (CDM)
Standard: JEDEC Standard JESD22-C101

MSL Rating

The part is rated Moisture Sensitivity Level 3 at 260°C per JEDEC standard IPC/JEDEC J-STD-020.

Solderability

The plating material on the pins is annealed matte tin over copper.

Compatible with both lead-free (maximum 260 °C reflow temperature) and tin/lead (maximum 245 °C reflow temperature) soldering processes.

This part is compliant with EU 2002/95/EC RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment).

This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A ($C_{15}H_{12}Br_4O_2$) Free
- PFOS Free
- SVHC Free

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations, and information about TriQuint:

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